## THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: JAWARANI, DHARMESH		§ Patent No	.: 7262105 B2	
		s § Issue Dat	e: 4/4/2006	
Application No.: 10/718892		9 § Examiner	: Carl Whitehead, Jr.	
Filed:	11-21-2003	§ Patent No § Issue Dat § Examiner § Group Art § Docket No	t Unit: 2813	
Title:	§ Docket No.: SC13038TP SEMICONDUCTOR DEVICE WITH SILICIDED SOURCE/DRAINS			
	Certificate of Submission  I hereby certify that this correspondence is being submitted to I  USPTO, Alexandria, VA.			
	Addressed per C.F.R. § 1.1(a) and deposited with the United States Postal Service with sufficient postage as first class mail.			
			ccordance with C.F.R. §1.6(d).	
		Submitted electronically v	ia EFS in accordance with "Legal	
		Telegrap 26,2008  Date of Submission  Less Less Land		
		Signature Terese Shepi	hard	
		Printed Name of Person Signing Certificate		

Commissioner for Patents Alexandria, VA 22313

## SUBMISSION OF CERTIFICATE OF CORRECTION

Dear Commissioner:

Enclosed is a Certificate of Correction listing error(s) in the subject patent.

Please enter these corrections. Since the error(s) appear to be on the part of the Applicant, the required fee will be charged to Deposit Account 503079 via the Electronic Filing System.

<u>Egf, 25, 20</u>08 Data Respectfully submitted,

CLINGÀN, JR. JAMES L. Attorney for Applicant(s) Registration No. 30163

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(Also Form PTO-1050)

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CERTIFICATE OF CORRECTION				
	Page 1 of 1			
PATENT NO.:	7262105 B2			
APPLICATION NO:	10/718892			
DATE:	11-21-2003			
FIRST NAMED INVENTOR:	JAWARANI, DHARMESH			
It is certified that error appears in the above-identified patent and that said Letters  Patent are hereby corrected as shown below:				
In Column 5, Line 38, Claim No. 9:				
Change "implanting the is" toin	nplanting the germanium is—			
In Column 5, Line 64, Claim No. 16: Remove "partieles"				
In Column 6, Line 3, Claim No. 17:				
Change "implanting of the further includes" to—implanting of the germanium further includes				
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MAILING ADDRESS OF SENDER (Please do not use customer number below) Freescale Semiconductor, Inc.

Law Department 7700 West Parmer Lane PL02 Austin, TX 78729